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ATTORNEY DOCKET NO. CONFIRMATION NO. FIRST NAMED INVENTOR FILING DATE APPLICATION NO. Hideaki Yamasaki 33082M121 9824 10/049,283 02/11/2002 EXAMINER 7590 01/09/2004 HASSANZADEH, PARVIZ Smith Gambrell & Russell Beveridge DeGrandi Weilacher & Young PAPER NUMBER ART UNIT Intellectual Property Group 1850 M Street NW Suite 800 1763 Washington, DC 20036

Please find below and/or attached an Office communication concerning this application or proceeding.

			A
/	Applicati n No.	Applicant(s)	
Office Action Summary	10/049,283	YAMASAKI ET AL.	
	Examin r	Art Unit	
	Parviz Hassanzadeh	1763	
The MAILING DATE of this c mmunication ap Peri d for Reply	opears on the cover sheet with the c	rrespondence address	
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a report of the provision of the period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by statured to the period by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status	. 136(a). In no event, however, may a reply be tin ply within the statutory minimum of thirty (30) day of will apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication D (35 U.S.C. § 133).	n.
1) Responsive to communication(s) filed on 14 I	November 2003.		
2a)⊠ This action is FINAL . 2b)□ This	s action is non-final.		
3) Since this application is in condition for allows closed in accordance with the practice under			6
Disp sition of Claims			
 4) Claim(s) 1-12 is/are pending in the application 4a) Of the above claim(s) is/are withdrases 5) Claim(s) is/are allowed. 6) Claim(s) 1-12 is/are rejected. 7) Claim(s) 11 and 12 is/are objected to. 8) Claim(s) are subject to restriction and/or 	awn from consideration.		
Application Papers			
9) ☐ The specification is objected to by the Examin 10) ☑ The drawing(s) filed on is/are: a) ☐ acc Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the E	cepted or b) \boxtimes objected to by the lead rawing(s) be held in abeyance. Section is required if the drawing(s) is objection is $\sum_{i=1}^{n} a_i = a_i$	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d	1).
Priority under 35 U.S.C. §§ 119 and 120			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat * See the attached detailed Office action for a list 13) Acknowledgment is made of a claim for domest since a specific reference was included in the first 37 CFR 1.78. a) ☐ The translation of the foreign language profiled the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included in the first sentence of the foreign was included.	ats have been received. Its have been received in Applicationity documents have been received in Applicationity documents have been received (PCT Rule 17.2(a)). It of the certified copies not received tic priority under 35 U.S.C. § 119(a) is sentence of the specification or rovisional application has been received priority under 35 U.S.C. §§ 120	on No ed in this National Stage ed. e) (to a provisional applicati in an Application Data She eived. and/or 121 since a specific	eet.
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal P	(PTO-413) Paper No(s) atent Application (PTO-152) actions.	

DETAILED ACTION

Drawings

The proposed drawings were received on 11/14/03. These drawings are approved by the Examiner.

New corrected Formal drawings are required in this application.

Claim Objections

The numbering of claims is not in accordance with 37 CFR 1.126 which requires the original numbering of the claims to be preserved throughout the prosecution. When claims are canceled, the remaining claims must not be renumbered. When new claims are presented, they must be numbered consecutively beginning with the number next following the highest numbered claims previously presented (whether entered or not).

Misnumbered claims 12 and 13 been renumbered 11 and 12, respectively.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-6 are rejected under 35 U.S.C. 102(b) as being anticipated by Lee et al (US Patent No. 5,711,815).

Lee et al teach a film-forming unit (Fig. 14) comprising:

a processing container (chamber 70) in which a vacuum can be created;

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a stage (table 84) arranged in the processing container, on which an object (semiconductor wafer S) to be processed is placed;

a process-gas supplying means (gas supply pipe 81 connected to a gas introducing chamber 82 having gas diffusion plate 83) for supplying a process gas into the processing container;

a heating means (heating chamber 101) for heating the object to be processed placed on the stage;

a division wall (projection 71a of sidewall 71) that surrounds a lateral side and a lower side of the stage;

an inert-gas supplying means (purge gas supply paths 75) for introducing an inert gas into a stage-side region surrounded by the division wall; and

a gap-forming member whose inner peripheral portion is arranged above (higher than) a peripheral portion of the object to be processed placed on the stage via a gap and whose outer peripheral portion is arranged above (higher than) the division wall via a gap (ring member 90 including an annular press ring portion 91 formed to cover the entire peripheral edge portion of the wafer, and contact portions 92 provided at intervals in a circumferential direction and forming gap between the wafer and the portion 91, wherein a gap E between portion 91 and wafer is about 10 µm-200 µm and the gap between the portion 91 and upper surface of protrusion wall 71a is about 0.5 mm-3mm, see Fig. 16) (column 9, line 6 through column 10, line 48).

Further regarding claims 2, 4, 5, 6: ring member 90 including an annular press ring portion 91 formed to cover the entire peripheral edge portion of the wafer, and contact portions 92 provided at intervals in a circumferential direction, wherein a gap E between portion 91 and

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wafer is about 10 µm-200 µm and the gap between the portion 91 and upper surface of protrusion wall 71a is about 0.5 mm-3 mm, see Fig. 16 (column 9, line 63 through column 10, line 14).

Further regarding claim 3: ring member 90 is vertically movable by a drive mechanism 94 (column 10, lines 43-48).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claim 7 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al (US Patent No. 5,711,815) in view of Eisuke et al (JP 09186095A).

Lee et al teach all limitations of the claims as discussed above and further including a circulation path 72 of cooling water for cooling the process chamber 70 (column 9, lines 40-71); however, Lee et al fail to explicitly teach a controller for setting a temperature of the processing chamber to be higher than a condensation temperature of the process gas and lower than a decomposition temperature and reaction temperature of the process gas.

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Eisuke et al teach a film forming apparatus wherein heating medium is fed to the wall of a reaction chamber 9 so as not to condense CVD gas to prevent the formation of a reaction film onto the wall (abstract).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to set the temperature of the container as taught by Eisuke et al so that not to condense CVD gas in order to prevent the formation of the reaction film to the chamber.

Claim 8 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al (US Patent No. 5,711,815) in view of Asako et al (JP 09316644A).

Lee et al teach all limitations of the claims as discussed except for controller for setting a temperature of the process-gas supplying device to be higher than a condensation temperature of the process gas and lower than a decomposition temperature and a reaction temperature of the process gas.

Asako et al teach film forming apparatus wherein a showerhead nozzle 11 including passages 15 for flowing therethrough a heat exchange fluid thereby controlling the temperature of the showerhead (abstract).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to implement the temperature controlling mechanism as taught by Asako et al in the apparatus of Lee et al in order to set the temperature of the gas supplying device so that not to condense CVD gas in order to prevent the formation of the reaction film to the chamber.

Claim 9 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al (US Patent No. 5,711,815) in view of Moslehi (US Patent No. 5,400,209).

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Lee et al teach all limitations of the claims as discussed except for an electrostatic chuck provided in the stage.

Moslehi teaches a wafer support including a chuck 30 for electrostatically supporting a wafer 22 (abstract, Fig. 1, column 3, lines 29 through column 4, line 32).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to implement the electrostatic chuck as taught by Moslehi in the apparatus of Lee et al in order to support the wafer electrostatically.

Claims 10 and 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al (US Patent No. 5,711,815) in view of Toshikatsu (JP 09260469A).

Lee et al teach all limitations of the claims as discussed except for the gap forming member is provided with a heater and a thermocouple.

Toshikatsu teaches a vacuum treatment apparatus wherein a clamp 9 and a clamp holding member 12 including a heater wire 14 for heating the member to a prescribed temperature.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to implement the heating mechanism as taught by Toshikatsu in the apparatus of Lee et al in order to heat the gap forming member to a prescribed temperature.

Claim 12 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lee et al (US Patent No. 5,711,815).

Lee et al teach all limitations of the claims as discussed above except for the radial length of the outer peripheral portion of the gap-forming member being greater than the radial length of the inner peripheral portion of the gap-forming member.

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It was held in re Gardner v. TEC Systems, Inc., 725 F.2d 1338, 220 USPQ 777 (Fed. Cir. 1984), cert. denied, 469 U.S. 830, 225 USPQ 232 (1984) that where the only difference between the prior art and the claims was a recitation of relative dimensions of the claimed device and a device having the claimed relative dimensions would not perform differently than the prior art device, the claimed device was not patentably distinct from the prior art device.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to choose the length of the outer peripheral portion greater than the inner peripheral portion such that the purge gas flow is directed away (as shown in Fig. 12) from the substrate surface and thus does not disturb the uniformity of deposition process on the substrate.

Response to Arguments

Applicant's arguments filed 11/14/03 have been fully considered but they are not persuasive.

Applicants assert that "an outer peripheral portion of the gap-forming member is arranged above the divisional wall via a gap" which is not aught by Lee et al.

Examiner argues that the word "above" may be interpreted as "higher than" rather than "vertically directly over". Furthermore, Examiner argues that Lee at al (as recited in claims 1 and 7) does not restrict the outer peripheral portion of the gap-forming member not extending horizontally to be directly (vertically) above the division wall. The gap-forming member shown in embodiment of Fig. 16 may have an outer peripheral portion as shown in embodiment of Fig. 12 wherein the outer peripheral portion is horizontally extended to be directly (vertically) above the division wall such that purging gas flow follows a pattern as shown by the arrow in the drawing.

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Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Matsuse et al (US Patent No. 5,997,651) teach a film forming apparatus (Fig. 1) including a purge gas port 71 and a division wall 66, and gap forming member 42;

Mizuno et al (US Patent No. 5,494,494) teach a film forming apparatus wherein a gap forming member 9 having a contact surface 10 as shown in Figs. 17-19); and

Cheng et al (US Patent No. 5,851,299) teach a film forming apparatus including a shield ring 50 (Fig. 5) and a purge gas port 16.

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Parviz Hassanzadeh whose telephone number is (571)272-1435. The examiner can normally be reached on Tuesday-Friday.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Gregory Mills can be reached on (571)272-1439. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0661.

Parviz Hassanzadeh Primary Examiner Art Unit 1763

January 5, 2004